NSN 5961-01-200-9691



Diode Semiconductor Device - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-200-9691 **Inclosure Material:** Glass **Overall Length:** 0.520 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.260 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.034 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 15.0 breakdown voltage, dc **Power Rating Per Characteristic:** 1.5 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Precious Material And Location:** Inner surface gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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